A Stable Disilacyclopropane: [1 + 2] Cycloaddition of the Silylene Si[(NCH₂Bu^t)₂C₆H₄-1,2] with a Silene

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Summary: The [1 + 2] cycloaddition of a "free" silylene, namely the bis(amino)silylene $Si[(NCH_2Bu^t)_2C_6H_4-1,2]$ (1), with an in situ generated silene afforded the stable disilacyclopropane 2: the molecular structure of 2 is supported by NMR spectroscopic data and confirmed by a single X-ray diffraction analysis.

As early as 1976 the first evidence of the formation of a disilacyclopropane in solution was reported by Seyferth and Duncan by treatment of 1-chloro-2-(bromonorcaranyl)tetramethyldisilane with LiBuⁿ. The resulting 1,1,2,2-tetramethyl-3-norcaranylidene-1,2-disilacyclopropane (A) was not stable at ambient temper-



ature but could be trapped with MeOH.¹ It is surprising that up to now only three other disilacyclopropanes have been isolated (**B** and **C**), $^{2-4}$ only one of which was characterized by X-ray crystallographic analysis (B with $Ar = o-Xyl)^2$ Other compounds containing the SiSiC ring fragment are the disilacyclopropanmethylene species \mathbf{D}^5 and the disilacyclopropanimine $\mathbf{E}^{.6}$

In this communication we report the addition of a "free" silylene, namely the thermally stable Si[(NCH₂- $Bu^{t}_{2}C_{6}H_{4}$ -1,2] (1),⁷ to a Si–C double bond to afford the stable disilacyclopropane 2.

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Scheme 1



The readily available transient silene 4 can be obtained in situ by thermolysis of the 1,2-disilacyclobutane **3**.⁸ Thus, by treatment of **3** with **1** in refluxing benzene for 2 days the disilirane 2 was obtained in 82% yield (Scheme 1).⁹ No reaction was observed between 3 and **1** at ambient temperature.

The structure of **2** has been elucidated by an X-ray crystallographic determination and consists of two independent molecules; only one is shown and discussed (Figure 1).¹⁰ The Si(1)-Si(2) bond length of 2.2749(10) Å in the disilirane ring is relatively short compared to Si-Si single bonds (average 2.358 Å)¹¹ but is in the same range which was observed for the Si-Si bond in **B** (2.272(2) Å).² In comparison the Si–Si bond distance in the SiSiC ring containing a methylene (**D**) or imine fragment (E) is somewhat longer $(2.327(2) \text{ Å } (D)^5 \text{ or})$

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⁽⁹⁾ Experimental data for 2: a solution of 1 (1.27 mmol, 0.35 g) in benzene (20 mL) was added to a solution of 3 (0.63 mmol, 0.39 g) in benzene (20 mL), and the mixture was refluxed for 48 h. The solvent was removed, and the remaining solid was crystallized from hexane at -25 °C to yield the yellow crystalline **2** (0.61 g, 82%); mp 139-141 °C. ¹H NMR (300 MHz, C₆D₆): δ 0.42 (s, SiMe₃, 18 H), 1.03 (s, Bu^t, 18 ⁶C. ¹H NMR (300 MHz, C₆D₆): δ 0.42 (s, SiMe₃, 18 H), 1.03 (s, Bu', 18 H), 1.58–1.97 (m, adamantyl, 14 H), 3.25, 3.29, 3.35, and 3.51 (AB type, 4 H, CH₂) and 6.86 (br s, Ph, 4 H). ¹³C{¹H} NMR (75.48 MHz, C₆D₆): δ 3.7 (SiMe₃), 29.2 (CMe₃), 36.1 (CMe₃), 28.0, 29.5, and 31.5 (CH adamanyl), 37.2, 38.0 and 39.5 (CH₂-adamantyl), 31.5 (C_q adamantyl), 53.3 (CH₂), 111.0, 117.7, and 139.8 (phenyl). ²⁹Si{¹H} NMR (99.33 MHz, C₆D₆): δ –86.9 (NNS1), –10.3 (SiMe₃) and 0.9 (SiSiMe₃). MS: m/z 584 (M⁺). Anal. Calcd for C₃₂H₅₈N₂Si₄: C, 65.9; H, 10.02; N, 4.8 Found: C, 65.9; H 10.12: N, 4.74 4.8. Found: C, 65.9; H, 10.12; N, 4.74.

⁽¹⁰⁾ Crystal data for **2**: $C_{32}H_{58}N_2Si_4$, $M_r = 583.16$, specimen 0.2 × (10) Crystal data for 2. C₃₂₁₁₅₈₁₂₅₄₄, M_T = 365.10, specified 0.2 × 0.15 × 0.05 mm³, monoclinic, space group $P_{2,1}/n$ (No. 14), a = 18.9066-(3) Å, b = 18.7310(3) Å, c = 22.4504(3) Å, $\beta = 114.720$ (1), U = 7222.0-(2) Å³, Z = 8, $\mu = 0.19$ mm⁻¹, T = 223(2) K, 9904 unique reflections collected, R1 = 0.045 for 7223 reflections with $I > 2\sigma(I)$, wR2 = 0.188 for all reflections. Data collection: KappaCCD, full-matrix leastsquares refinement on F², SHELX-97.

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Figure 1. Molecular structure of **2**. Selected bond lengths (Å) and angles (deg) (two independent molecules, only one shown): Si(1)-Si(2) = 2.2749(10), Si(1)-C(17) = 1.879(3), Si(2)-C(17) = 1.980(3), Si(1)-N(1) = 1.732(2), Si(1)-N(2) = 1.742(2), Si(2)-Si(3) = 2.3726(12), Si(2)-Si(4) = 2.3650-(12); Si(1)-C(17)-Si(2) = 72.2(10), Si(1)-Si(2)-C(17) = 51.84(8), Si(2)-Si(1)-C(17) = 55.96(8), N(1)-Si(1)-N(2) = 92.33(11), Si(4)-Si(2)-Si(3) = 123.49(4).

2.328(3) Å (**E**)⁶). The environment at the Si atoms shows little pyramidalization. The sums of bond angles at Si-(1) and Si(2) are 357.76 and 354.99°, respectively, with Si(1) being 0.783 Å out of the Si(2)Si(3)Si(4) plane and Si(2) being 0.459 Å out of the N(1)N(2)Si(1) plane.

The ²⁹Si NMR signal at δ –86.9 for the N₂Si silicon is particularly highly shielded and can be compared to

the even more shielded $(Me_3Si)_2Si$ silicon of **C** (δ -118.5)⁴ and the less shielded silicons in **B** (δ -65.97, Ar = Mes),³ **D** (δ -48.5, R = Ph),⁵ and **C** (δ -35.6, SiMe₂).⁴ Unusual, however, is the downfield-shifted ²⁹Si resonance of the $(Me_3Si)_2Si$ silicon in **2** at δ 0.9, which could be attributed to the influence of the nitrogen substitution at Si(1).

Previous strategies for the synthesis of SiSiC threemembered-ring structures involved (i) cyclization via a Grignard-type reaction (**A**),¹ (ii) addition of Mes₂Si to a 1-silapropadiene (both photolytically generated) (**C**),⁵ (iii) addition of a carbene equivalent $(CH_2N_2)^{2.3}$ or carbene-like carbon compound (isonitrile)⁶ to a Si–Si double bond (**B** or **C**), and (iv) the addition of a transient silylene to a Si–C double bond (**C**).⁴ However, strategy iii could also proceed via 1,3-dipolar cycloaddition of the diazomethane with subsequent loss of nitrogen, as in the case of reactions of disilenes with azides,¹² and for strategy iv the reaction of a "free" silylene with the silene could not be established; **C** could also have been formed by reaction of the silirane used as the silylene precursor and the silene.⁴

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Supporting Information Available: Tables giving X-ray data for **2**; these data are also available as a CIF file. This material is available free of charge via the Internet at http://pubs.acs.org.

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